

Power TOPLED Hyper-Bright LED

LS E676, LO E676, LY E676



Vorläufige Daten / Preliminary Data

Besondere Merkmale

- **Gehäusotyp:** weißes P-LCC-4 Gehäuse
- **Besonderheit des Bauteils:** höhere Umgebungstemperatur bei gleichem Strom zulässig im Vergleich zur TOPLED
- **Wellenlänge:** 633 nm (super-rot), 606 nm (orange), 587 nm (gelb)
- **Abstrahlwinkel:** Lambertscher Strahler (120°)
- **Technologie:** InGaAlP
- **optischer Wirkungsgrad:** 8 lm/W (super-rot), 12 lm/W (orange, gelb)
- **Gruppierungsparameter:** Lichtstärke, Wellenlänge, Durchflussspannung
- **Verarbeitungsmethode:** für alle SMT-Bestücktechniken geeignet
- **Lötmethode:** IR Reflow Löten und Wellenlöten (TTW)
- **Vorbehandlung:** nach JEDEC Level 2
- **Gurtung:** 8 mm Gurt mit 2000/Rolle, ø180 mm oder 8000/Rolle, ø330 mm
- **ESD-Festigkeit:** ESD-sicher bis 2 kV nach EOS/ESD-5.1-1993

Anwendungen

- Ampelanwendung
- Hinterleuchtung (LCD, Schalter, Tasten, Displays, Werbebeleuchtung, Allgemeinbeleuchtung)
- Innenbeleuchtung im Automobilbereich (z.B. Instrumentenbeleuchtung, u.ä.)
- Ersatz von Kleinstglühlampen
- Signal- und Symbolleuchten
- Scanner

Features

- **package:** white P-LCC-4 package
- **feature of the device:** higher ambient temperature at the same current possible compared to TOPLED
- **wavelength:** 633 nm (super-red), 606 nm (orange), 587 nm (yellow)
- **viewing angle:** Lambertian Emitter (120°)
- **technology:** InGaAlP
- **optical efficiency:** 8 lm/W (super-red), 12 lm/W (orange, yellow)
- **grouping parameter:** luminous intensity, wavelength, forward voltage
- **assembly methods:** suitable for all SMT assembly methods
- **soldering methods:** IR reflow soldering and TTW soldering
- **preconditioning:** acc. to JEDEC Level 2
- **taping:** 8 mm tape with 2000/reel, ø180 mm or 8000/reel, ø330 mm
- **ESD-withstand voltage:** up to 2 kV acc. to EOS/ESD-5.1-1993

Applications

- traffic lights
- backlighting (LCD, switches, keys, displays, illuminated advertising, general lighting)
- Interior automotive lighting (e.g. dashboard backlighting, etc.)
- substitution of micro incandescent lamps
- signal and symbol luminaire
- scanners

Typ	Emissions- farbe	Farbe der Lichtaustritts- fläche	Lichtstärke	Lichtstrom	Bestellnummer
Type	Color of Emission	Color of the Light Emitting Area	Luminous Intensity $I_F = 30 \text{ mA}$ $I_V \text{ (mcd)}$	Luminous Flux $I_F = 30 \text{ mA}$ $\Phi_V \text{ (mlm)}$	Ordering Code
LS E676-P2Q2-1 LS E676-Q2S1-1	super-red	colorless clear	56 ... 112 90 ... 224	240 (typ.) 440 (typ.)	Q62703-Q5767 Q62703-Q5768
LO E676-R1S1-1 LO E676-S1T2-1	orange	colorless clear	112 ... 224 180 ... 450	490 (typ.) 880 (typ.)	Q62703-Q5765 Q62703-Q5766
LY E676-R2S2-11 LY E676-S2U1-11	yellow	colorless clear	140 ... 280 180 ... 560	610 (typ.) 1100 (typ.)	Q62703-Q5119 Q62703-Q5120

Anm.: -11 gesamter Farbbereich, Lieferung in Einzelgruppen (siehe **Seite 5**)
 -11 gesamter Durchlassspannungsbereich, Lieferung in Einzelgruppen (siehe **Seite 5**)

*Die Standardlieferform von Serientypen beinhaltet eine untere bzw. eine obere Familiengruppe, die aus nur 3 bzw. 4 Halbgruppen besteht. Einzelne Halbgruppen sind nicht erhältlich.
 In einer Verpackungseinheit / Gurt ist immer nur eine Halbgruppe enthalten.*

Note: -11 Total color tolerance range, delivery in single groups (please see **page 5**)
 -11 Total forward voltage tolerance delivery in single groups (see **page 5**).

*The standard shipping format for serial types includes a lower or upper family group of 3 or 4 individual half groups. Individual half groups are not available.
 No packing unit / tape ever contains more than one luminous intensity half group.*

Grenzwerte
Maximum Ratings

Bezeichnung Parameter	Symbol Symbol	Werte Values		Einheit Unit
		LS, LO	LY	
Betriebstemperatur Operating temperature range	T_{op}	– 40 ... + 100		°C
Lagertemperatur Storage temperature range	T_{stg}	– 40 ... + 100		°C
Sperrschichttemperatur Junction temperature	T_{j}	+ 125		°C
Durchlassstrom Forward current	I_{F}	40		mA
Stoßstrom Surge current $t \leq 10 \mu\text{s}$, $D = 0.005$	I_{FM}	1	0.2	A
Sperrspannung Reverse voltage	V_{R}	5		V
Leistungsaufnahme Power consumption $T_{\text{A}} \leq 25 \text{ °C}$	P_{tot}	110		mW
Wärmewiderstand Thermal resistance Sperrschicht/Umgebung Junction/ambient	$R_{\text{th JA}}$	300		K/W
Sperrschicht/Lötpad Junction/solder point Montage auf PC-Board FR 4 (Padgröße $\geq 16 \text{ mm}^2$) mounted on PC board FR 4 (pad size $\geq 16 \text{ mm}^2$)	$R_{\text{th JS}}$	130		K/W

Kennwerte ($T_A = 25\text{ °C}$)
Characteristics

Bezeichnung Parameter	Symbol Symbol	Werte Values			Einheit Unit
		LS	LO	LY	
Wellenlänge des emittierten Lichtes (typ.) Wavelength at peak emission $I_F = 30\text{ mA}$	λ_{peak}	645	610	591	nm
Dominantwellenlänge ¹⁾ (typ.) Dominant wavelength $I_F = 30\text{ mA}$	λ_{dom}	633 ± 6	606 ± 6	587 +8/-7	nm
Spektrale Bandbreite bei 50 % $I_{\text{rel max}}$ (typ.) Spectral bandwidth at 50 % $I_{\text{rel max}}$ $I_F = 30\text{ mA}$	$\Delta\lambda$	16	16	15	nm
Abstrahlwinkel bei 50 % I_V (Vollwinkel) (typ.) Viewing angle at 50 % I_V	2ϕ	120	120	120	Grad deg.
Durchlassspannung ²⁾ (typ.) Forward voltage $I_F = 30\text{ mA}$	V_F (max.) V_F	2.0 2.4	2.0 2.4	2.0 2.4	V V
Sperrstrom (typ.) Reverse current $V_R = 3\text{ V}$	I_R (max.) I_R	0.01 10	0.01 10	0.01 10	μA μA
Temperaturkoeffizient von λ_{peak} (typ.) Temperature coefficient of λ_{peak} $I_F = 30\text{ mA}; -10^\circ\text{C} \leq T \leq 100^\circ\text{C}$	$TC_{\lambda_{\text{peak}}}$	0.14	0.13	0.13	nm/K
Temperaturkoeffizient von λ_{dom} (typ.) Temperature coefficient of λ_{dom} $I_F = 30\text{ mA}; -10^\circ\text{C} \leq T \leq 100^\circ\text{C}$	$TC_{\lambda_{\text{dom}}}$	0.01	0.07	0.10	nm/K
Temperaturkoeffizient von V_F (typ.) Temperature coefficient of V_F $I_F = 30\text{ mA}; -10^\circ\text{C} \leq T \leq 100^\circ\text{C}$	TC_V	- 2.0	- 1.7	- 2.5	mV/K
Optischer Wirkungsgrad (typ.) Optical efficiency $I_F = 30\text{ mA}$	η_{opt}	8	12	12	lm/W

¹⁾ Wellenlängengruppen werden mit einer Stromeinprägedauer von 25 ms und einer Genauigkeit von $\pm 1\text{ nm}$ ermittelt.
Wavelength groups are tested at a current pulse duration of 25 ms and a tolerance of $\pm 1\text{ nm}$.

²⁾ Durchlassspannungsgruppen werden mit einer Stromeinprägedauer von 1 ms und einer Genauigkeit von $\pm 0,1\text{ V}$ ermittelt.
Forward voltage groups are tested at a current pulse duration of 1 ms and a tolerance of $\pm 0.1\text{ V}$.

¹⁾ Wellenlängengruppen für LY E676
Wavelength groups for LY E676

Gruppe Group	Durchlassspannung Forward voltage		Einheit Unit
	min.	max.	
2	580	583	nm
3	583	586	nm
4	586	589	nm
5	589	592	nm
6	592	595	nm

²⁾ Durchlassspannungsgruppen für LY E676
Forward voltage groups for LY E676

Gruppe Group	Wellenlänge Wavelength		Einheit Unit
	min.	max.	
3	1.8	2.1	V
4	2.1	2.4	V

Helligkeits-Gruppierungsschema
Luminous Intensity Groups

Lichtgruppe Luminous Intensity Group	Lichtstärke Luminous Intensity I_V (mcd)	Lichtstrom Luminous Flux Φ_V (lm)
P2	56 ... 71	190 (typ.)
Q1	71 ... 90	240 (typ.)
Q2	90 ... 112	300 (typ.)
R1	112 ... 140	380 (typ.)
R2	140 ... 180	480 (typ.)
S1	180 ... 224	600 (typ.)
S2	224 ... 280	760 (typ.)
T1	280 ... 355	950 (typ.)
T2	355 ... 450	1200 (typ.)
U1	450 ... 560	1500 (typ.)

Helligkeitswerte werden mit einer Stromeinprägungsdauer von 25 ms und einer Genauigkeit von $\pm 11\%$ ermittelt.
Luminous intensity is tested at a current pulse duration of 25 ms and a tolerance of $\pm 11\%$.

Gruppenbezeichnung auf Etikett
Group Name on Label

Beispiel: T1-34

Example: T1-34

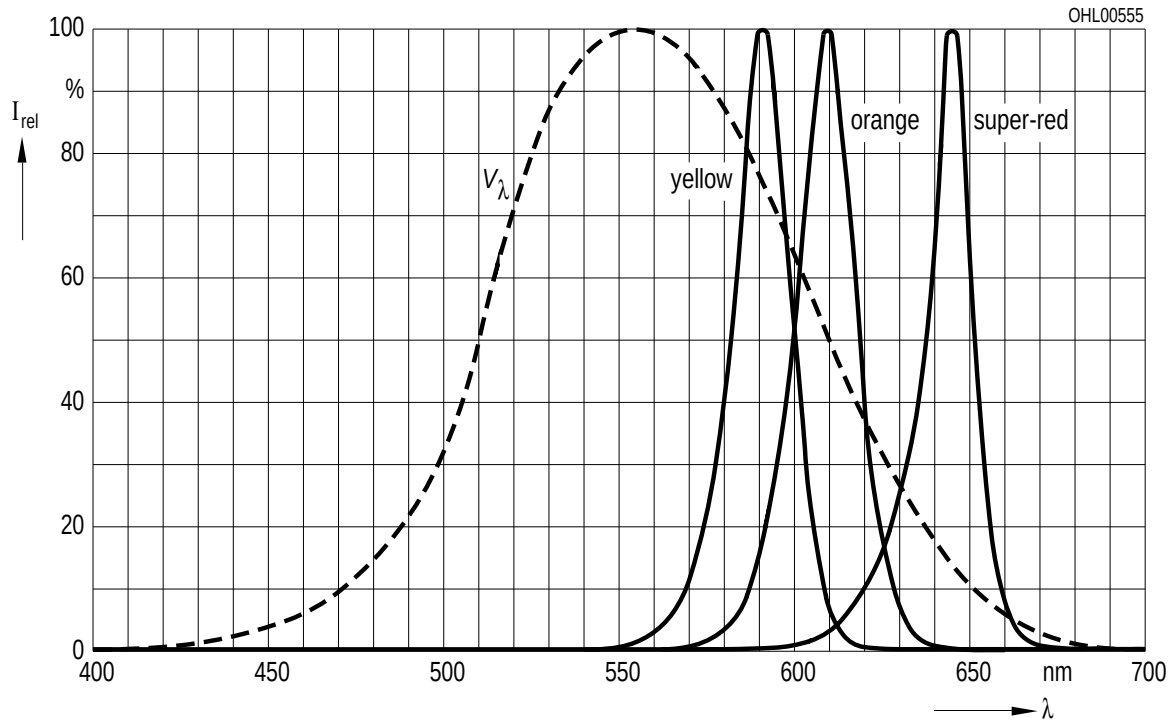
Lichtgruppe Luminous Intensity Group	Halbgruppe Half Group	Wellenlänge Wavelength	Durchlassspannung Forward Voltage
T	1	3	4

Relative spektrale Emission $I_{\text{rel}} = f(\lambda)$, $T_A = 25^\circ\text{C}$, $I_F = 30\text{ mA}$

Relative Spectral Emission

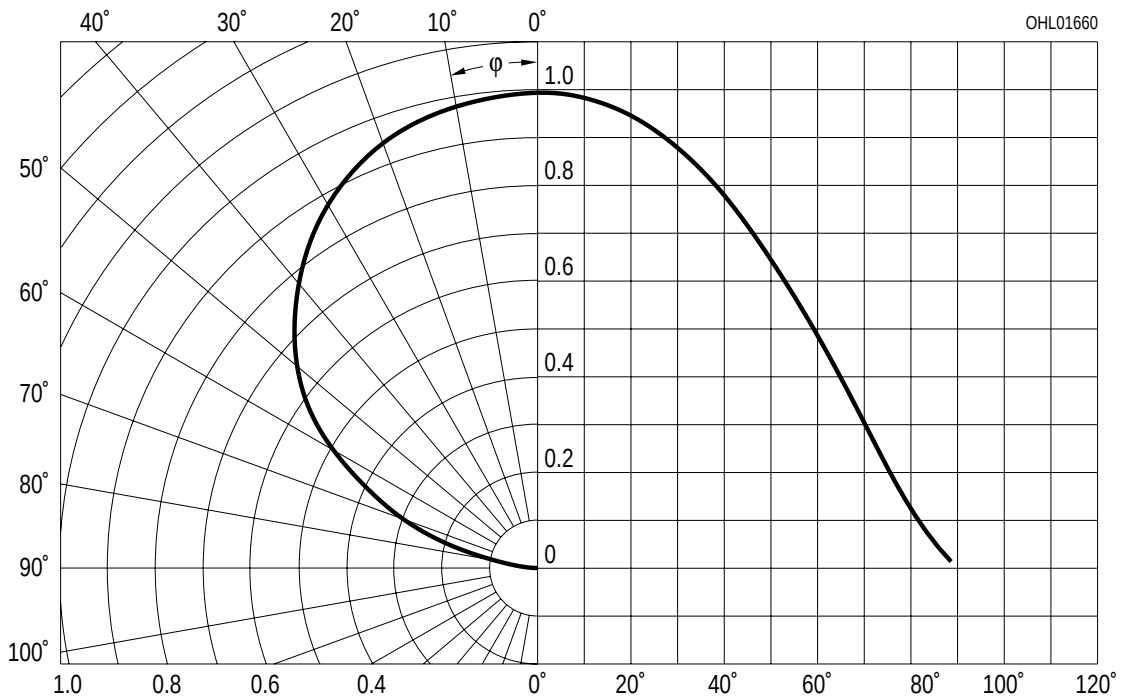
$V(\lambda)$ = spektrale Augenempfindlichkeit

Standard eye response curve



Abstrahlcharakteristik $I_{\text{rel}} = f(\varphi)$

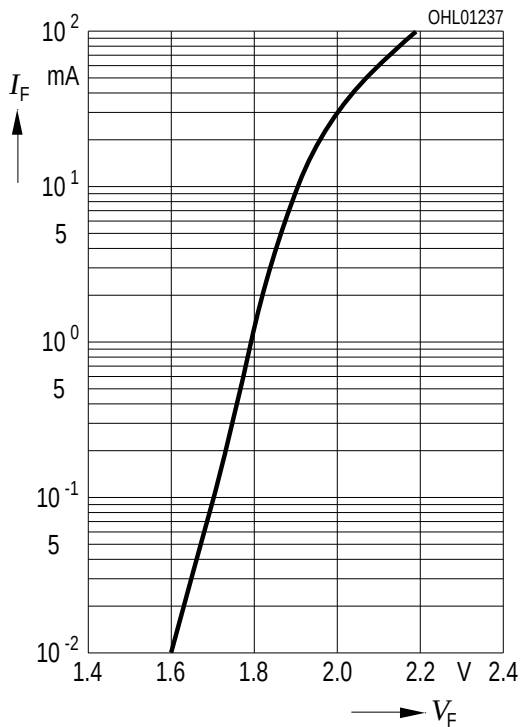
Radiation Characteristic



Durchlassstrom $I_F = f(V_F)$

Forward Current

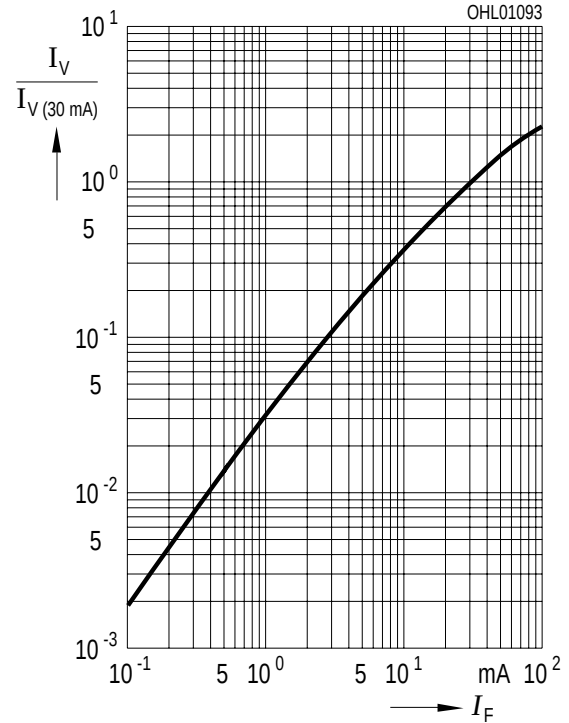
$T_A = 25^\circ\text{C}$



Relative Lichtstärke $I_V/I_{V(30\text{ mA})} = f(I_F)$

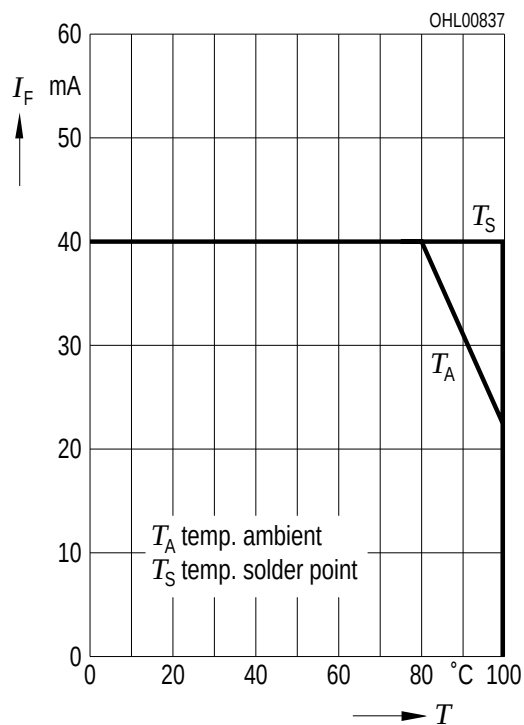
Relative Luminous Intensity

$T_A = 25^\circ\text{C}$



Maximal zulässiger Durchlassstrom $I_F = f(T)$

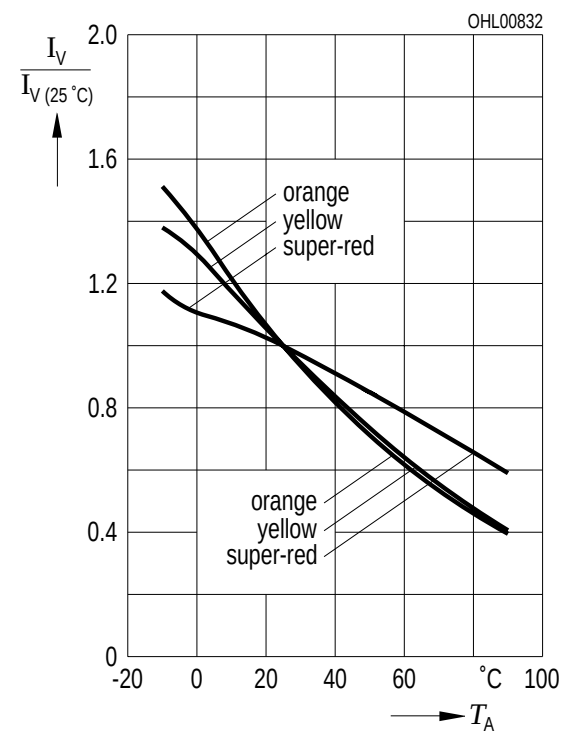
Max. Permissible Forward Current



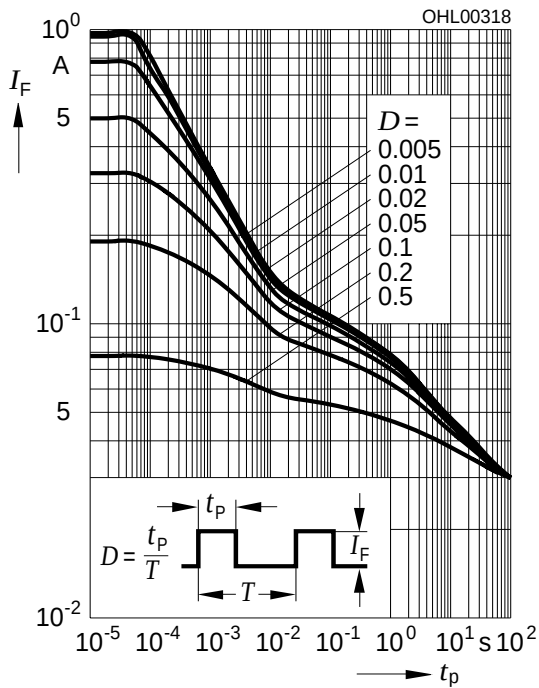
Relative Lichtstärke $I_V/I_{V(25^\circ\text{C})} = f(T_A)$

Relative Luminous Intensity

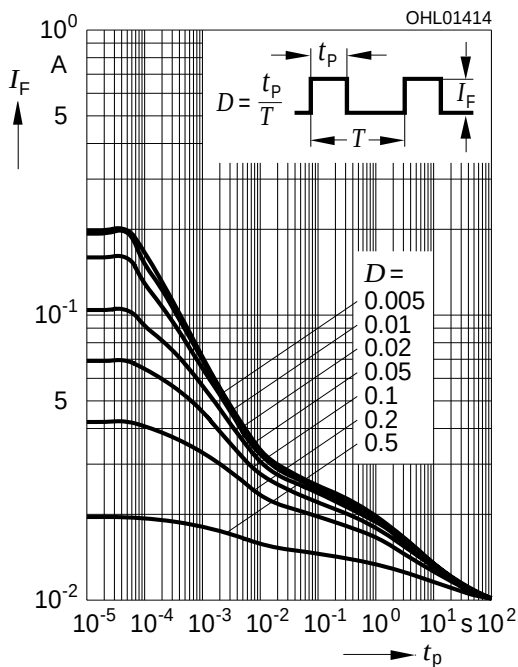
$I_F = 30\text{ mA}$



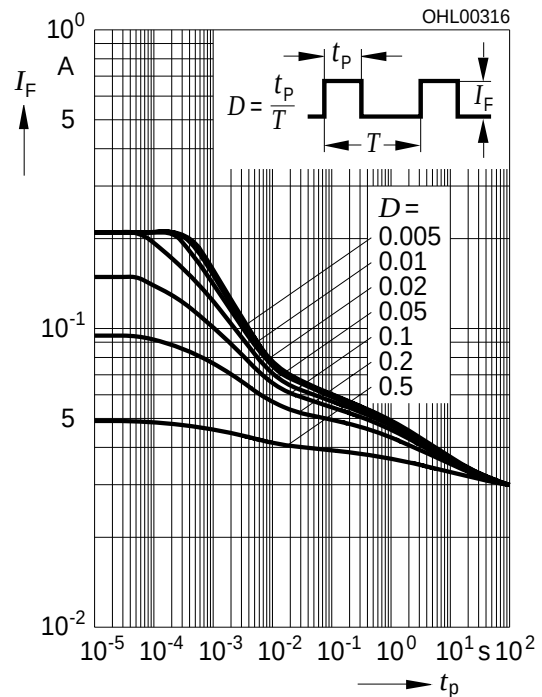
Zulässige Impulsbelastbarkeit $I_F = f(t_p)$
Permissible Pulse Handling Capability
Duty cycle $D =$ parameter, $T_A = 25\text{ °C}$
LS, LO



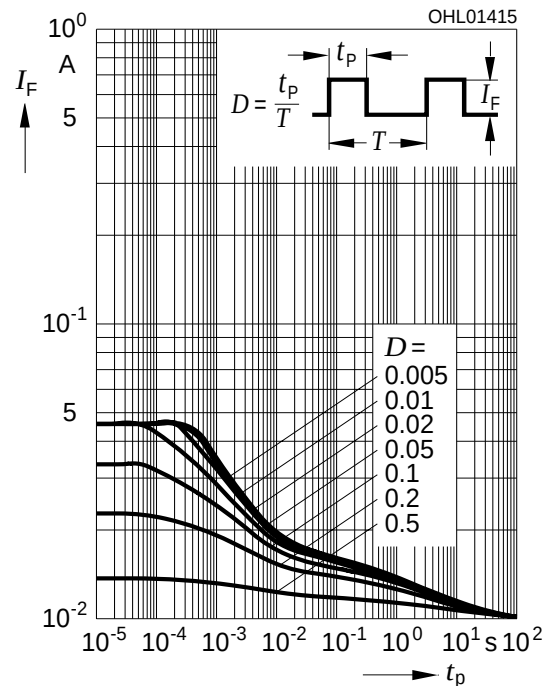
Zulässige Impulsbelastbarkeit $I_F = f(t_p)$
Permissible Pulse Handling Capability
Duty cycle $D =$ parameter, $T_A = 85\text{ °C}$
LS, LO



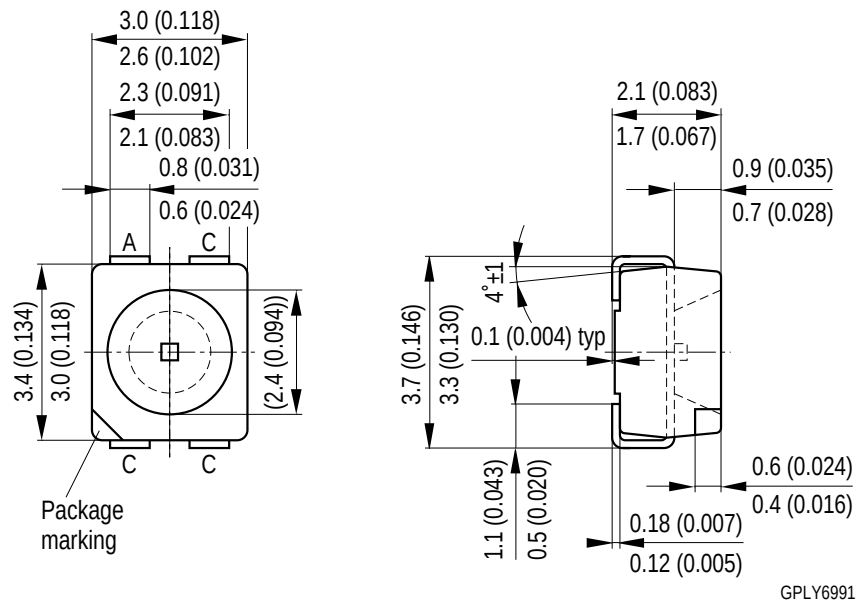
Zulässige Impulsbelastbarkeit $I_F = f(t_p)$
Permissible Pulse Handling Capability
Duty cycle $D =$ parameter, $T_A = 25\text{ °C}$
LY



Zulässige Impulsbelastbarkeit $I_F = f(t_p)$
Permissible Pulse Handling Capability
Duty cycle $D =$ parameter, $T_A = 85\text{ °C}$
LY



Maßzeichnung Package Outlines

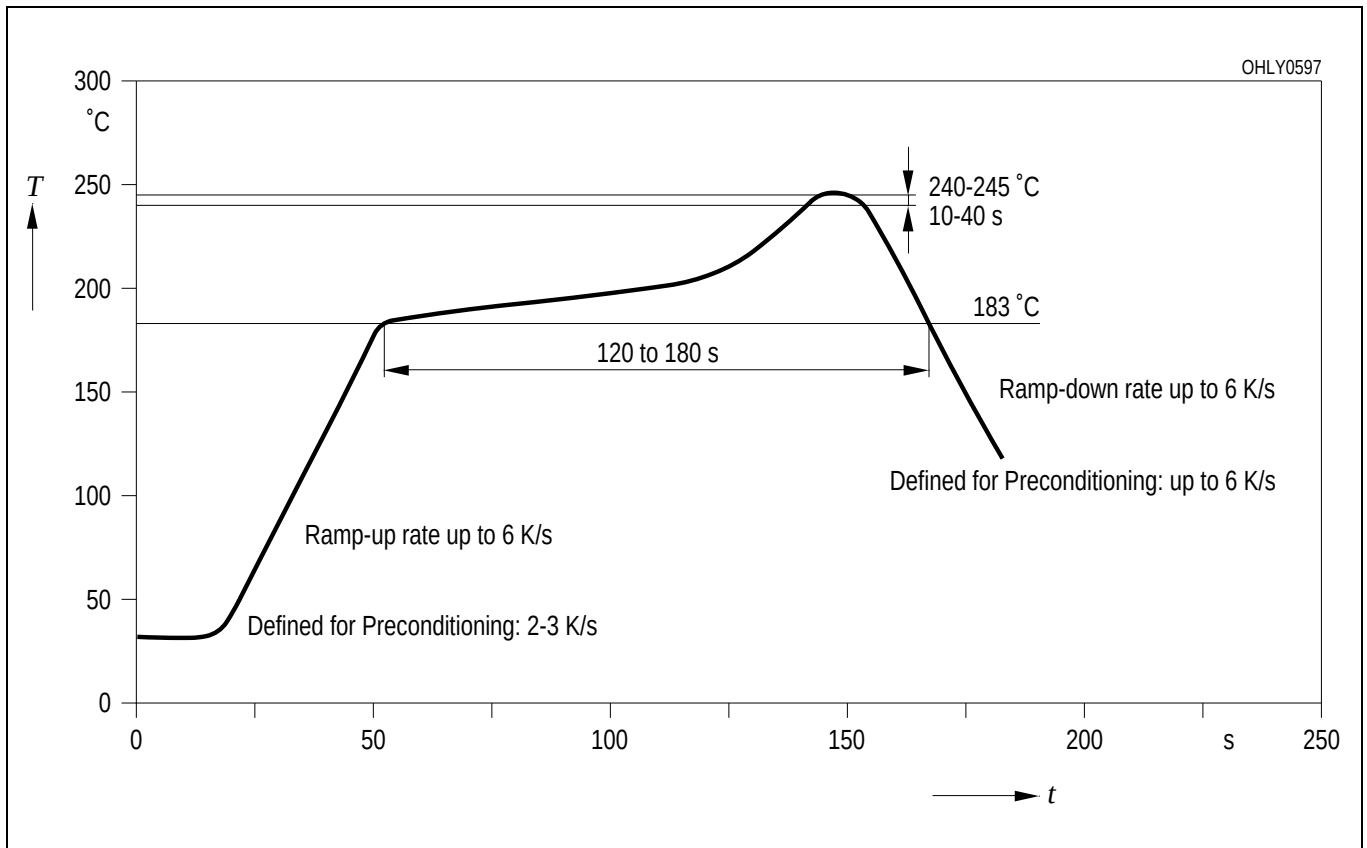


Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

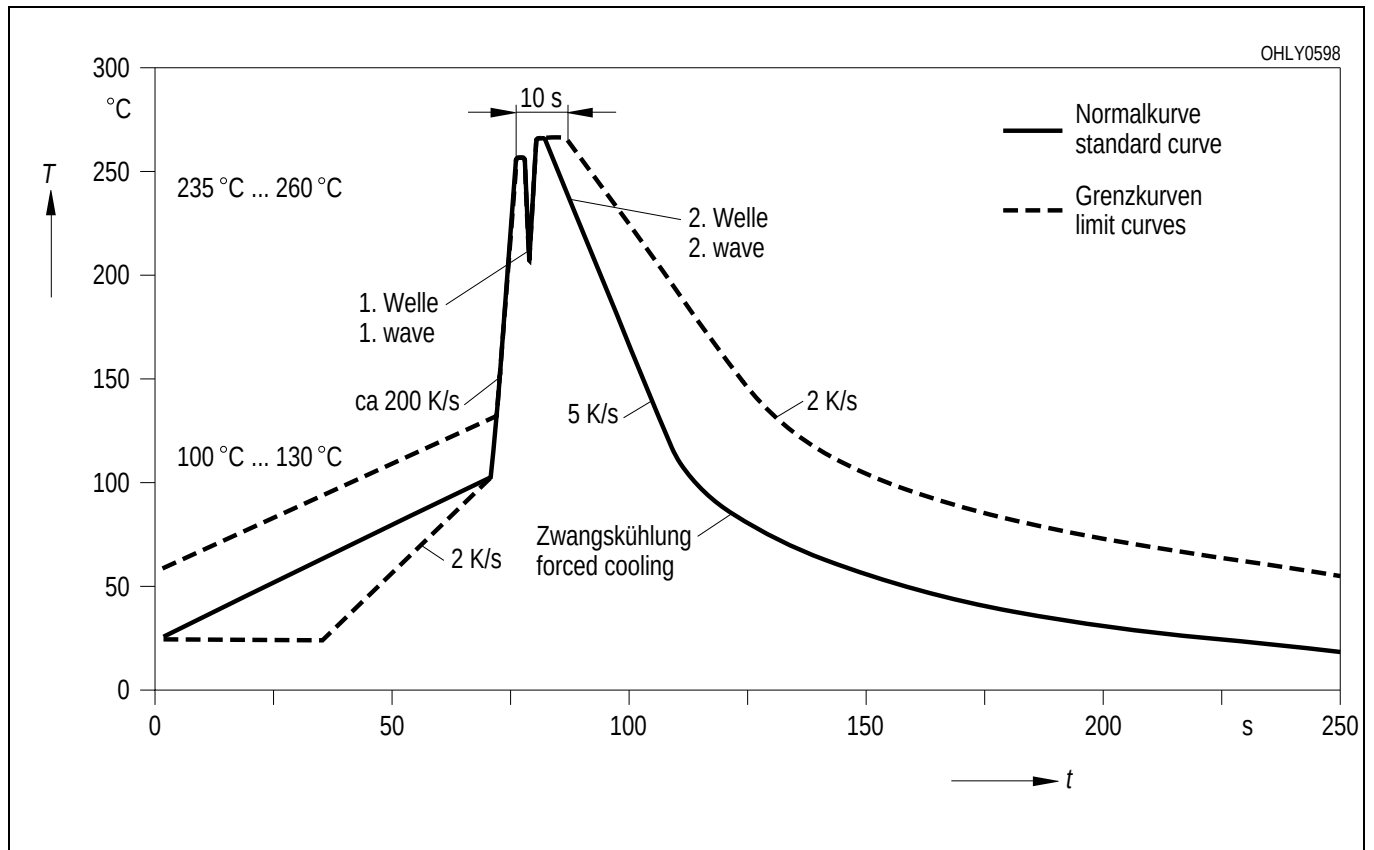
Gewicht / Approx. weight: 31 mg

Lötbedingungen Vorbehandlung nach JEDEC Level 2
Soldering Conditions Preconditioning acc. to JEDEC Level 2

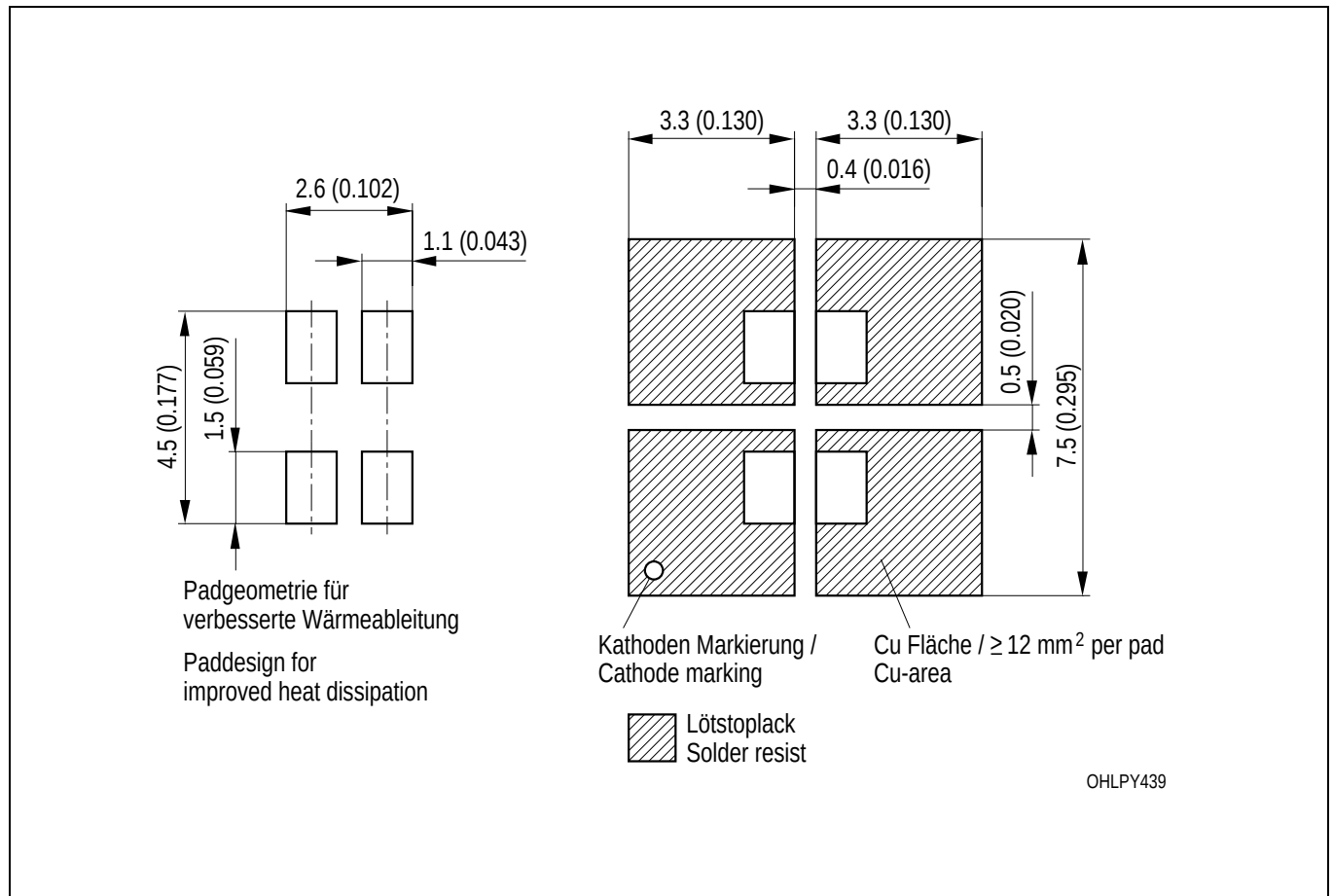
IR-Reflow Lötprofil (nach IPC 9501)
IR Reflow Soldering Profile (acc. to IPC 9501)



Wellenlöten (TTW) (nach CECC 00802)
TTW Soldering (acc. to CECC 00802)

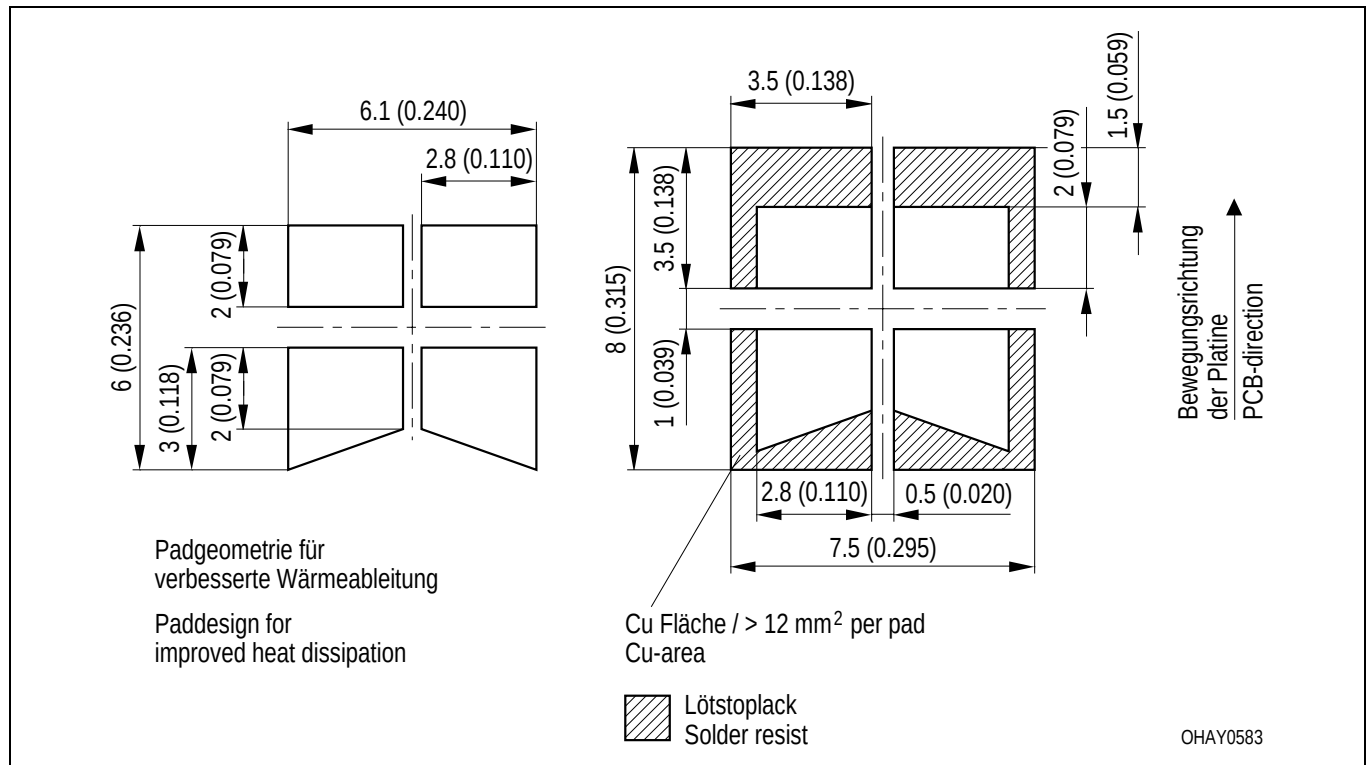


Empfohlenes Lötpaddesign IR Reflow Löten
Recommended Solder Pad IR Reflow Soldering



Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

Empfohlenes Lötpaddesign Wellenlöten (TTW)
Recommended Solder Pad TTW Soldering



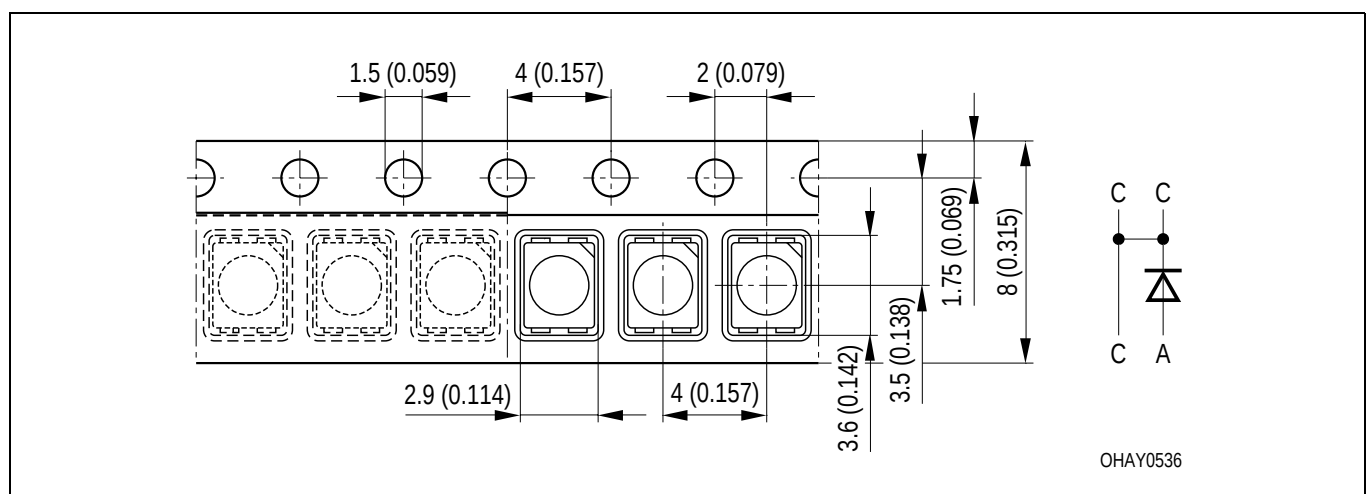
Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

Gurtung / Polarität und Lage

Verpackungseinheit 2000/Rolle, ø180 mm
oder 8000/Rolle, ø330 mm

Method of Taping / Polarity and Orientation

Packing unit 2000/reel, ø180 mm
or 8000/reel, ø330 mm



Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

Revision History: 2001-02-13

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Page	Subjects (major changes since last revision)

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Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

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